VB40M120C Vishay General Semiconductor

# **Dual High Voltage Trench MOS Barrier Schottky Rectifier**

Ultra Low  $V_F = 0.46$  V at  $I_F = 5$  A



click logo to get started

www.vishay.com

**DESIGN SUPPORT TOOLS** 



PRIMARY CHARACTERISTICS			
I <sub>F(AV)</sub>	2 x 20 A		
V <sub>RRM</sub>	120 V		
I <sub>FSM</sub>	250 A		
$V_F$ at $I_F = 20$ A	0.64 V		
T <sub>J</sub> max.	150 °C		
Package	D <sup>2</sup> PAK (TO-263AB)		
Circuit configuration	Common cathode		

### FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- COMPLIANT HALOGEN FREE Available

RoHS

 Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### TYPICAL APPLICATIONS

For use in solar cell junction box as a bypass diode for protection, using DC forward current without reverse bias.

### **MECHANICAL DATA**

Case: D<sup>2</sup>PAK (TO-263AB) Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS-compliant, commercial grade Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 and M3 suffix meets JESD 201 class 2 whisker test **Polarity:** as marked

MAXIMUM RATINGS (T<sub>A</sub> = 25 °C unless otherwise noted) PARAMETER SYMBOL VB40M120C UNIT Maximum repetitive peak reverse voltage 120 V V<sub>RRM</sub> 40 per device Maximum average forward rectified current (fig. 1) I<sub>F(AV)</sub> per diode 20 А Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode 250 I<sub>FSM</sub> Voltage rate of change (rated V<sub>R</sub>) dV/dt 10 000 V/µs Operating junction and storage temperature range T<sub>J</sub>, T<sub>STG</sub> -40 to +150 °C

<b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I <sub>F</sub> = 5 A	T <sub>A</sub> = 25 °C	- V <sub>F</sub> <sup>(1)</sup>	0.54	-	- V	
	I <sub>F</sub> = 10 A			0.64	-		
	I <sub>F</sub> = 20 A			0.79	0.89		
	I <sub>F</sub> = 5 A	T <sub>A</sub> = 125 °C		0.46	-		
	I <sub>F</sub> = 10 A			0.54	-		
	I <sub>F</sub> = 20 A			0.64	0.72		
Reverse current per diode	V <sub>R</sub> = 90 V	T <sub>A</sub> = 25 °C	I <sub>R</sub> <sup>(2)</sup>	4	-	μA	
		T <sub>A</sub> = 125 °C		3	-	mA	
	$V_{\rm P} = 120  {\rm V}$	T <sub>A</sub> = 25 °C		-	500	μA	
		T <sub>A</sub> = 125 °C		6	32	mA	

#### Notes

<sup>(1)</sup> Pulse test: 300 µs pulse width, 1 % duty cycle

<sup>(2)</sup> Pulse test: Pulse width  $\leq$  20 ms

 Revision: 20-Jun-2018
 1
 Document Number: 89468

 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com
 THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



VB40M120C

## Vishay General Semiconductor

<b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)				
PARAMETER	SYMBOL	VB40M120C	UNIT	
Typical thermal resistance per diode	$R_{ ext{ heta}JC}$	1.8	°C/W	

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-263AB	VB40M120C-E3/4W	1.39	4W	50/tube	Tube		
TO-263AB	VB40M120C-E3/8W	1.39	8W	800/reel	Tape and reel		
TO-263AB	VB40M120C-M3/I	1.39	I	800/reel	Tape and reel		

## RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)

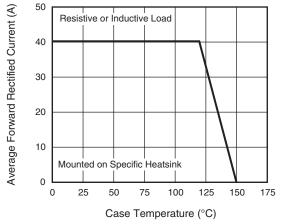


Fig. 1 - Maximum Forward Current Derating Curve

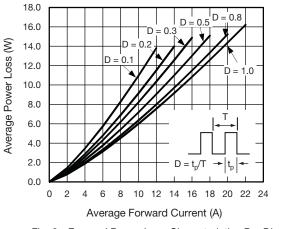


Fig. 2 - Forward Power Loss Characteristics Per Diode

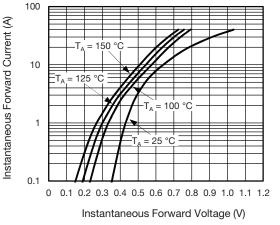


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

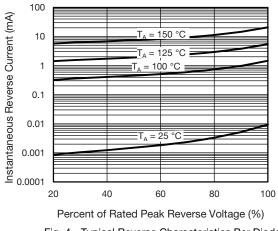


Fig. 4 - Typical Reverse Characteristics Per Diode

Revision: 20-Jun-2018

2

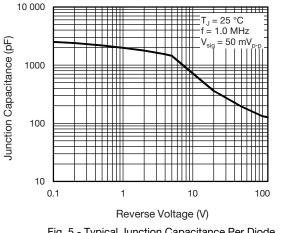
Document Number: 89468

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

# VB40M120C



## Vishay General Semiconductor



#### Fig. 5 - Typical Junction Capacitance Per Diode

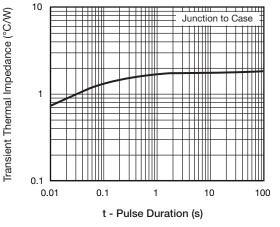
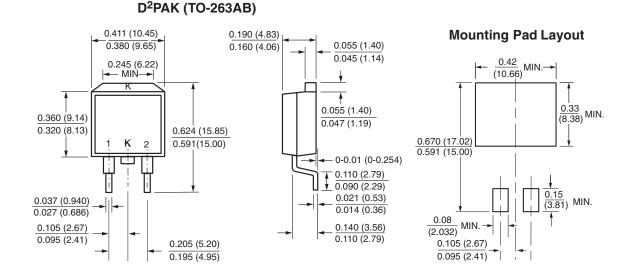


Fig. 6 - Typical Transient Thermal Impedance Per Diode





Revision: 20-Jun-2018 Document Number: 89468 For technical questions within your region: DiodesAmericas@vishav.com, DiodesAsia@vishav.com, DiodesEurope@vishav.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishav.com/doc?91000



Vishay

## Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Vishay products are not designed for use in life-saving or life-sustaining applications or any application in which the failure of the Vishay product could result in personal injury or death unless specifically qualified in writing by Vishay. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

© 2025 VISHAY INTERTECHNOLOGY, INC. ALL RIGHTS RESERVED

Revision: 01-Jan-2025

1